

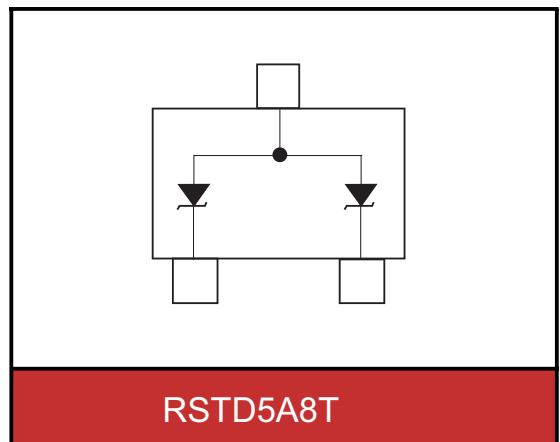
## DESCRIPTION

The RSTD5A8T is ultra low capacitance TVS arrays designed to protect high speed data interfaces. It has been specifically designed to protect sensitive components which is connected to high-speed data and transmission lines from overvoltage caused by electrostatic(ESD) , cable discharge events(CDE) and electrical fast transients(EFT). It has a typical capacitance of only 0.8pF(typ.). This means it can be used on circuits operating in excess of 3GHz without signal attenuation.

**HBM : ±8kV**  
**Air Mode : ±15kV**

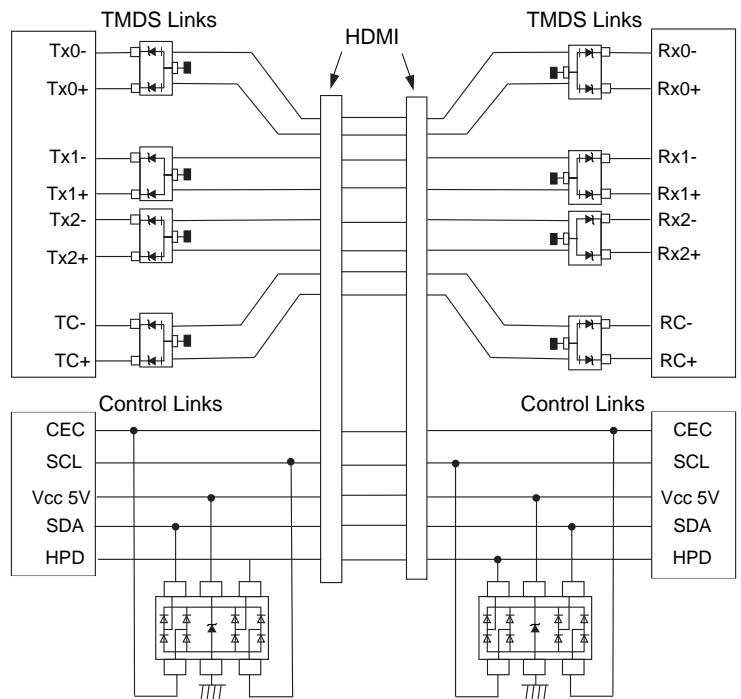
## SPECIFICATION FEATURES

- IEC61000-4-2 ESD 15KV Air,8KV contact compliance
- Small SOT-323 surface mount package
- Protects two high speed data lines
- Ultra low capacitance and clamping voltages
- Low leakage current
- Solid-state silicon avalanche technology
- Lead Free/RoHS compliant
- Solder reflow temperature:Pure Tin-Sn,260-270°C
- Flammability rating: UL 94V-0



## APPLICATIONS

- HDMI interface protection
- Mobile display digital interface
- RF/Antenna circuits
- USB 2.0 & Firewire ports
- GaAs photodetector protection
- HBT power Amp protection
- Infiniband transceiver protection



**MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Peak pulse power (tp=8/20μs waveform)	P <sub>PP</sub>	200	W
ESD voltage (HBM contact)	V <sub>ESD</sub>	±8	kV
ESD voltage (AIR contact)		±15	
Storage & operating temperature range	T <sub>STG</sub> , T <sub>J</sub>	-55~+150	°C

**ELECTRICAL CHARACTERISTICS (T<sub>J</sub>=25°C)**

RSTD5A8T (Marking:B BU)

Rating	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V <sub>RWM</sub>				5	V
Reverse breakdown voltage	V <sub>BR</sub>	I <sub>BR</sub> =1mA	6			V
Reverse leakage current	I <sub>R</sub>	V <sub>R</sub> =5V each I/O pin			1	μA
Clamping voltage (tp=8/20μs)	V <sub>C</sub>	I <sub>PP</sub> =1A			15	V
Off state junction capacitance	C <sub>J</sub>	0Vdc,f=1MHz Between I/O pins and GND		0.8		pF

## TYPICAL CHARACTERISTICS CURVES

Figure 1. Power Derating Curve

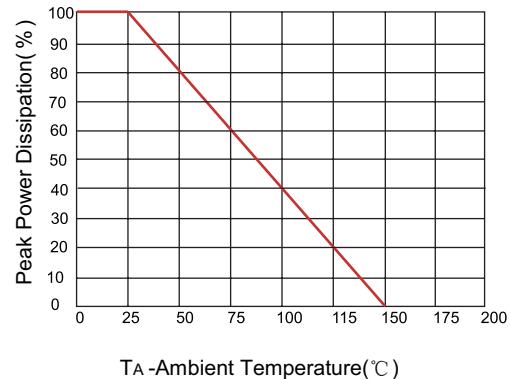


Figure 2. Pulse Waveforms

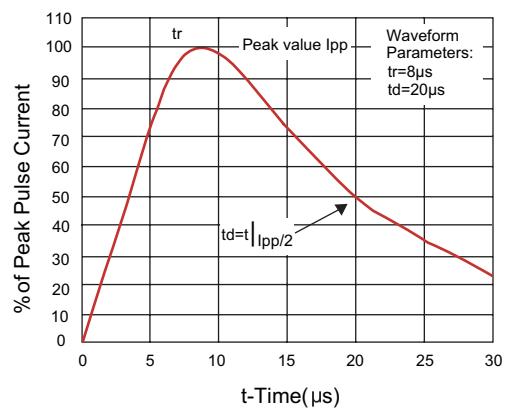


Figure 3. Non-Repetitive Peak Pulse vs Pulse Time

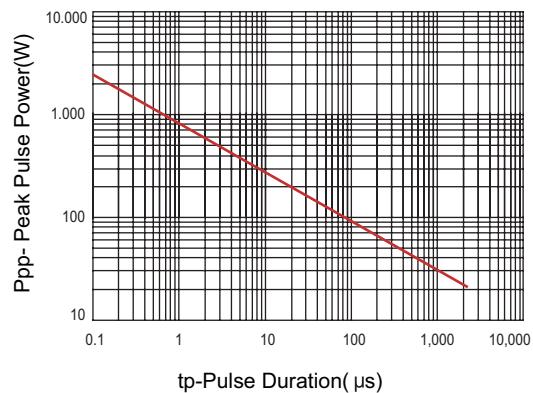
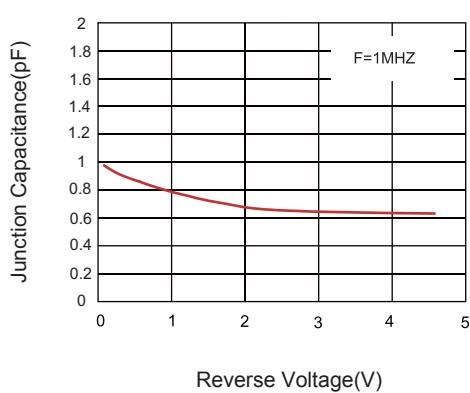
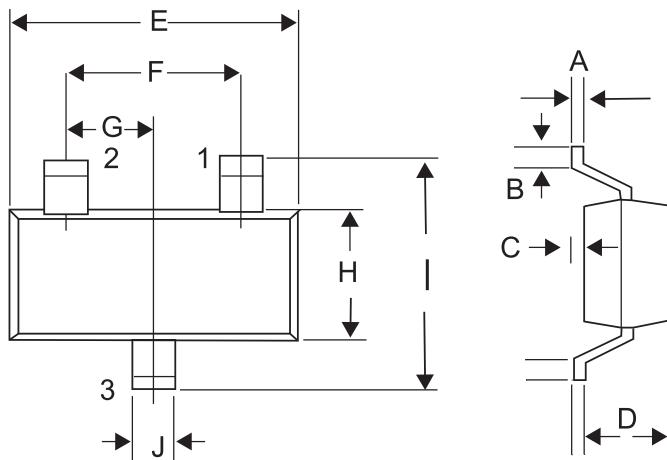


Figure 4. Capacitance vs. Reverse Voltage



## PACKAGE AND SUGGESTED PAD LAYOUT DIMENSION

**SOT-323(unit:mm)**

SYMBOL	DIMENSIONS			
	INCHES	MILLIMETERS	MIN	MAX
A	0.002	0.008	0.05	0.20
B	0.004	-	0.10	-
C	-	0.004	-	0.10
D	0.031	0.043	0.80	1.10
E	0.071	0.087	1.80	2.20
F	0.051		1.30	
G	0.026		0.65	
H	0.045	0.053	1.15	1.35
I	0.079	0.087	2.00	2.20
J	0.008	0.016	0.20	0.40

